

Vishay General Semiconductor

HALOGEN

FREE

Surface-Mount PAR® Transient Voltage Suppressors

High Temperature Stability and High Reliability Conditions



DO-218 Compatible



LINKS TO ADDITIONAL RESOURCES







PRIMARY CHARACTERISTICS					
V_{WM}	10 V to 85 V				
V_{BR}	11.1 V to 104 V				
P _{PPM} (10 x 1000 μs)	3600 W				
P _{PPM} (10 x 10 000 μs)	2800 W				
P_{D}	5 W				
I _{FSM}	500 A				
T _J max.	175 °C				
Polarity	Unidirectional				
Package	DO-218AC				

FEATURES

- Junction passivation optimized design passivated anisotropic rectifier technology
- T_J = 175 °C capability suitable for high reliability and automotive requirement
- Unidirectional
- · Low leakage current
- · Low forward voltage drop
- · High surge capability
- Meets ISO7637-2 surge specification (varied by test condition)
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C
- AEC-Q101 qualified available
 - Automotive ordering code: base P/NHM3
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

TYPICAL APPLICATIONS

Use in sensitive electronics protection against voltage transients induced by inductive load switching and lightning, especially for automotive load dump protection application.

MECHANICAL DATA

Case: DO-218AC

Molding compound meets UL 94 V-0 flammability rating Base P/NHM3 - RoHS-compliant, AEC-Q101 qualified

Terminals: matte tin plated leads, solderable per

J-STD-002 and JESD 22-B102

HM3 suffix meets JESD 201 class 2 whisker test

Polarity: heatsink is anode

MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted)						
PARAMETER	SYMBOL	VALUE	UNIT			
Peak pulse power dissipation	with 10/1000 µs waveform	D	3600	W		
	with 10/10 000 µs waveform	P _{PPM}	2800			
Power dissipation on infinite heats	sink at T _A = 25 °C (fig. 1)	g. 1) P _D		W		
Peak pulse current with 10/1000	us waveform	I _{PPM} ⁽¹⁾ See next table		Α		
Peak forward surge current 8.3 m	I _{FSM}	500	Α			
Operating junction and storage te	T _J , T _{STG}	-55 to +175	°C			

Note

(1) Non-repetitive current pulse at T_A = 25 °C



SM5S10AHM3 thru SM5S85AHM3

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ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)										
DEVICE TYPE	BREAKDOWN VOLTAGE V _{BR} (V)		TEST CURRENT I _T	STAND-OFF VOLTAGE V _{WM}	MAXIMUM REVERSE LEAKAGE AT V _{WM}	MAXIMUM REVERSE LEAKAGE AT V _{WM}	MAX. PEAK PULSE CURRENT AT 10/1000 μs	MAXIMUM CLAMPING VOLTAGE AT I _{PPM}	TYPICAL TEMP. COEFFICIENT OF V _{BR} ⁽¹⁾	
	MIN.	NOM.	MAX.	(mA)	(V)	I _D (μA)	T _J = 175 °C I _D (μΑ)	WAVEFORM (A)	V _C (V)	αT (%/°C)
SM5S10AHM3	11.1	11.7	12.3	5.0	10.0	15	250	212	17.0	0.069
SM5S11AHM3	12.2	12.9	13.5	5.0	11.0	10	150	198	18.2	0.072
SM5S12AHM3	13.3	14.0	14.7	5.0	12.0	10	150	181	19.9	0.074
SM5S13AHM3	14.4	15.2	15.9	5.0	13.0	10	150	167	21.5	0.076
SM5S14AHM3	15.6	16.4	17.2	5.0	14.0	10	150	155	23.2	0.078
SM5S15AHM3	16.7	17.6	18.5	5.0	15.0	10	150	148	24.4	0.080
SM5S16AHM3	17.8	18.8	19.7	5.0	16.0	10	150	138	26.0	0.081
SM5S17AHM3	18.9	19.9	20.9	5.0	17.0	10	150	130	27.6	0.082
SM5S18AHM3	20.0	21.1	22.1	5.0	18.0	10	150	123	29.2	0.083
SM5S20AHM3	22.2	23.4	24.5	5.0	20.0	10	150	111	32.4	0.085
SM5S22AHM3	24.4	25.7	26.9	5.0	22.0	10	150	101	35.5	0.086
SM5S24AHM3	26.7	28.1	29.5	5.0	24.0	10	150	92.5	38.9	0.087
SM5S26AHM3	28.9	30.4	31.9	5.0	26.0	10	150	85.5	42.1	0.088
SM5S28AHM3	31.1	32.8	34.4	5.0	28.0	10	150	79.3	45.4	0.089
SM5S30AHM3	33.3	35.1	36.8	5.0	30.0	10	150	74.4	48.4	0.090
SM5S33AHM3	36.7	38.7	40.6	5.0	33.0	10	150	67.5	53.3	0.091
SM5S36AHM3	40.0	42.1	44.2	5.0	36.0	10	150	62.0	58.1	0.091
SM5S40AHM3	44.4	46.8	49.1	5.0	40.0	10	150	55.8	64.5	0.092
SM5S43AHM3	47.8	50.3	52.8	5.0	43.0	10	150	51.9	69.4	0.093
SM5S45AHM3	50.0	52.7	55.3	5.0	45.0	10	150	49.5	72.7	0.093
SM5S48AHM3	53.3	56.1	58.9	5.0	48.0	10	150	46.5	77.4	0.093
SM5S51AHM3	56.7	59.7	62.7	5.0	51.0	10	150	43.7	82.4	0.093
SM5S54AHM3	60.0	63.2	66.3	5.0	54.0	10	150	41.3	87.1	0.093
SM5S58AHM3	64.4	67.8	71.2	5.0	58.0	10	150	38.5	93.6	0.093
SM5S60AHM3	66.7	70.2	73.7	5.0	60.0	10	150	37.2	96.8	0.093
SM5S64AHM3	71.1	74.9	78.6	5.0	64.0	10	150	35.0	103	0.093
SM5S70AHM3	77.8	81.9	86.0	5.0	70.0	10	150	31.9	113	0.093
SM5S75AHM3	83.3	87.7	92.1	5.0	75.0	10	150	29.8	121	0.093
SM5S78AHM3	86.7	91.3	95.8	5.0	78.0	10	150	28.6	126	0.093
SM5S85AHM3	94.4	99.2	104	5.0	85.0	10	150	26.3	137	0.093

Notes

⁽¹⁾ To calculate V_{BR} vs. junction temperature, use the following formula: V_{BR} at T_J = V_{BR} at 25 °C x (1 + αT x (T_J - 25))

THERMAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)							
PARAMETER	SYMBOL	VALUE	UNIT				
Typical thermal resistance	R _{0JA} (1)	55	°C/W				
Typical thermal resistance	R _{0JM} (2)	0.45	°C/W				

Notes

[•] For all types maximum $V_F = 2.0 \text{ V}$ at $I_F = 100 \text{ A}$ measured on 300 μs square pulse width

 $^{^{(1)} \ \} Thermal\ resistance\ junction-to-ambient\ to\ follow\ JEDEC@51-2A,\ device\ mounted\ on\ FR4\ PCB,\ 2\ oz.\ standard\ footprint$

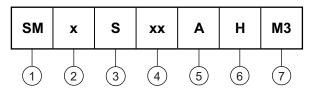
⁽²⁾ Thermal resistance junction-to-mount to follow JEDEC®51-14 using Transient Dual Interface Test Method (TDIM)

SM5S10AHM3 thru SM5S85AHM3

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ORDERING INFORMATION TABLE

Device code



1 - Surface mount

2 - Power dissipation P_D (5 = 5 W, 6 = 6 W, 8 = 8 W)

Standard V_F type

Stand-off voltage

5 - Breakdown voltage tolerance and polarity (A ± 5 %, unidirectional)

- Quality grade (H = AEC-Q101 qualified, otherwise = industry grade)

- Material / Environment category (M3 = halogen-free, RoHS-compliant, and termination lead (Pb)-free

ORDERING INFORMATION (Example)							
PREFERRED P/N	UNIT WEIGHT (g)	PREFERRED PACKAGE CODE	BASE QUANTITY	DELIVERY MODE			
SM5S10AHM3/I ⁽¹⁾	2.505	I	750	13" diameter plastic tape and reel, anode towards the sprocket hole			

Note

(1) AEC-Q101 qualified



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RATINGS AND CHARACTERISTICS CURVES (T_A = 25 °C unless otherwise noted)

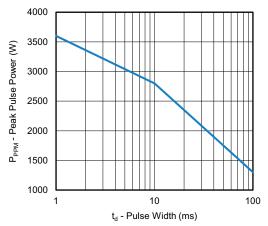


Fig. 1 - Peak Pulse Power Derating Curve

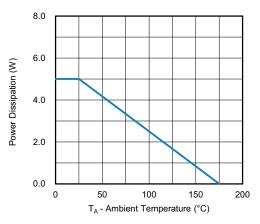


Fig. 2 - Power Derating Curve

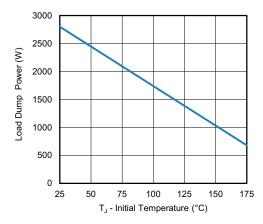


Fig. 3 - Load Dump Power Characteristics (10 ms Exponential Waveform)

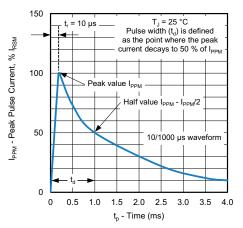


Fig. 4 - Pulse waveform

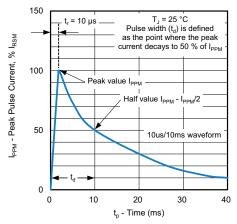


Fig. 5 - Pulse Waveform

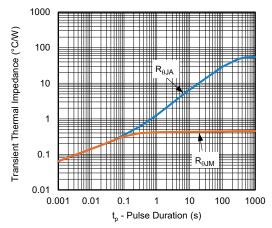


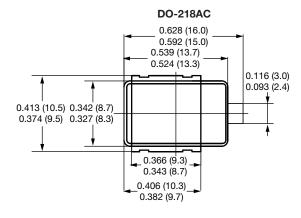
Fig. 6 - Typical Transient Thermal Impedance

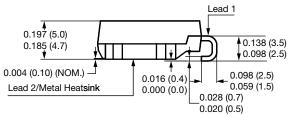




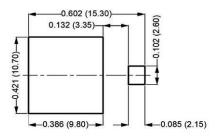
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PACKAGE OUTLINE DIMENSIONS in inches (millimeters)





Mounting Pad Layout



Note

• Footprint in accordance with IPC 7351 standard



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